

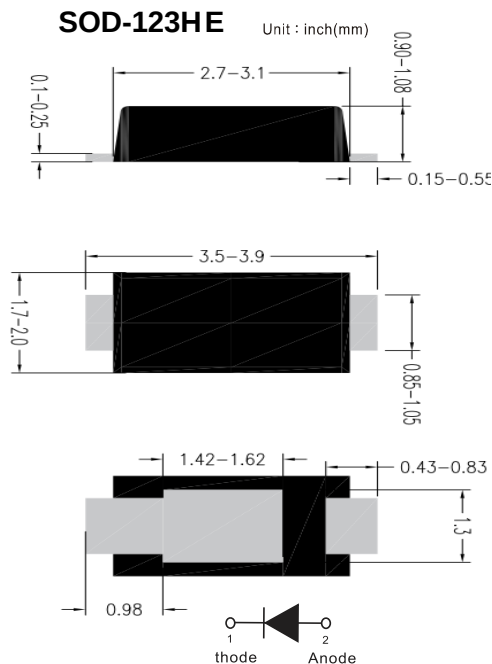
Surface Mount Fast Recovery Rectifier Diode

Features

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Fast switching for fast recovery
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

Mechanical Data

- **Package:** SOD-123HE
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** Cathode line denotes the cathode end



Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Unit	RS2AHE	RS2BHE	RS2DHE	RS2GHE	RS2JHE	RS2KHE	RS2MHE
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	V	50	100	200	400	600	800	1000
Maximum RMS Voltage	V_{RMS}	V	35	70	140	280	420	560	700
Maximum DC blocking Voltage	V_{DC}	V	50	100	200	400	600	800	1000
Average rectified output current @60Hz sine wave, Resistance load, TL (FIG.1)	I_O	A	2						
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave, 1 cycle, $T_j=25^\circ\text{C}$	I_{FSM}	A	45						
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, $T_j=25^\circ\text{C}$			90						
Current squared time @1ms≤t≤8.3ms $T_j=25^\circ\text{C}$	I^2t	A^2s	8.4						
Storage temperature	T_{stg}	°C	-55 ~ +150						
Junction temperature	T_j	°C	-55 ~ +150						

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Unit	Test Conditions	RS2AHE	RS2BHE	RS2DHE	RS2GHE	RS2JHE	RS2KHE	RS2MHE
Maximum instantaneous forward voltage	V _F	V	I _{FM} =2A	1.3						
Maximum reverse recovery time	t _{rr}	ns	I _F =0.5A, I _R =1.0A, I _{rr} =0.25A	150				250	500	
Maximum DC reverse current at rated DC blocking voltage	I _R	μA	T _j =25°C	5						
			T _j =125°C	100						
Typical junction capacitance	C _j	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	14				10		



Thermal Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Unit	RS2AHE	RS2BHE	RS2DHE	RS2GHE	RS2JHE	RS2KHE	RS2MHE
Typical Thermal resistance	$R_{\theta J-A}^{(1)}$	$^{\circ}\text{C/W}$	65						
	$R_{\theta J-L}^{(1)}$		30						
	$R_{\theta J-C}^{(1)}$		20						

Note:

(1) Thermal resistance between junction and ambient and between junction and lead mounted on P.C.B with 3mm*3mm copper pad areas.

Characteristics Curves

FIG1:Io-TL Curve

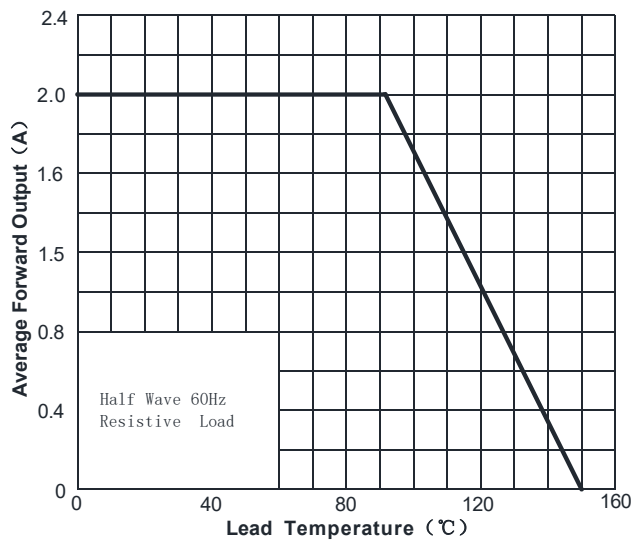


FIG2: Surge Forward Current Capability

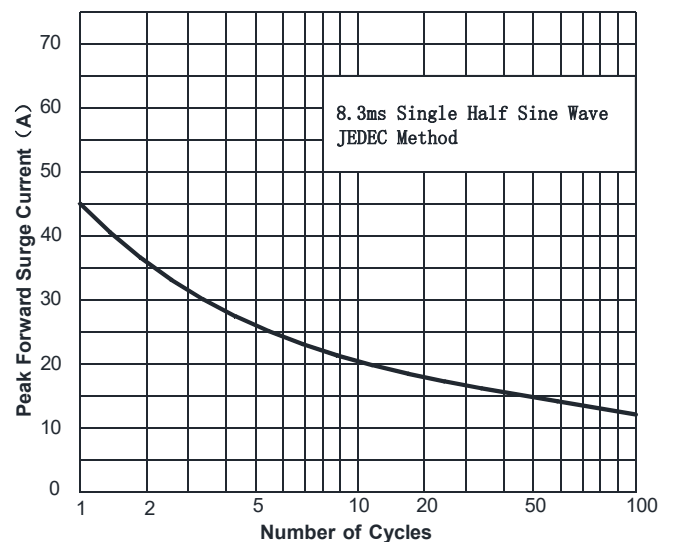


FIG3: Forward Voltage

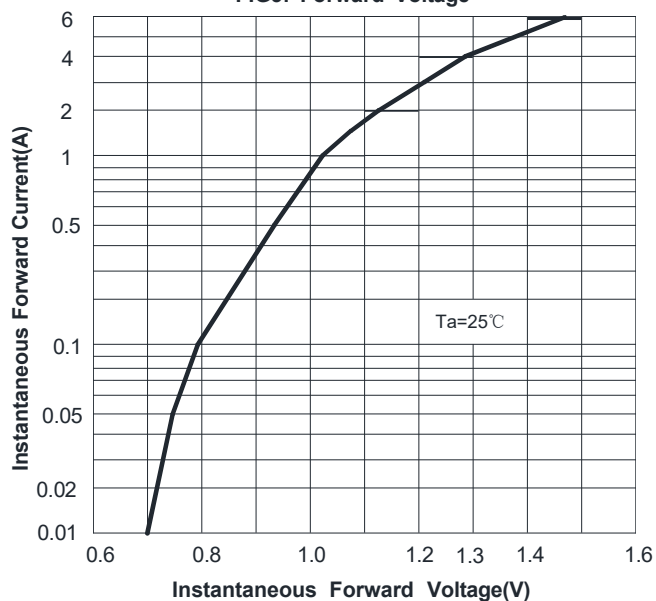


FIG4: Typical Reverse Characteristics

